TKMMBTA42

TRANSISTOR (NPN)

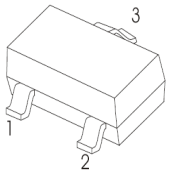
SOT-23 Plastic-Encapsulate Transistors

FEATURES

- High breakdown voltage
- Low collector-emitter saturation voltage
- Complementary to TKMMBTA92 (PNP)

Marking: 1D

SOT-23



1. BASE
2. EMITTER
3. COLLECTOR

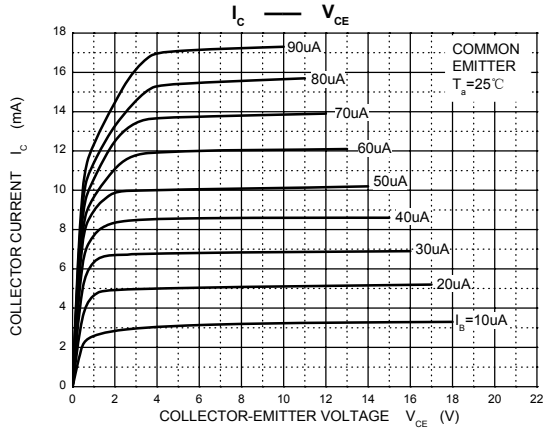
MAXIMUM RATINGS (T_a=25℃ unless otherwise noted)

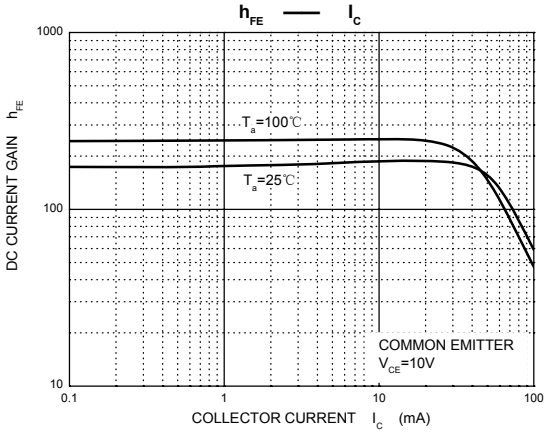
Symbol	Parameter	Value	Unit	
V_{CBO}	Collector-Base Voltage	300	V	
V_{CEO}	Collector-Emitter Voltage	300	V	
V_{EBO}	Emitter-Base Voltage	5	V	
I_C	Collector Current -Continuous	0.3	A	
I_{CM}	Collector Current-Peak	0.5	A	
P_C	Collector Power dissipation	0.35	W	
$R_{\theta JA}$	Thermal Resistance, junction to Ambient	357	℃/W	
T_J	Junction Temperature	150	℃	
T_{stg}	Storage Temperature	-55~+150	℃	

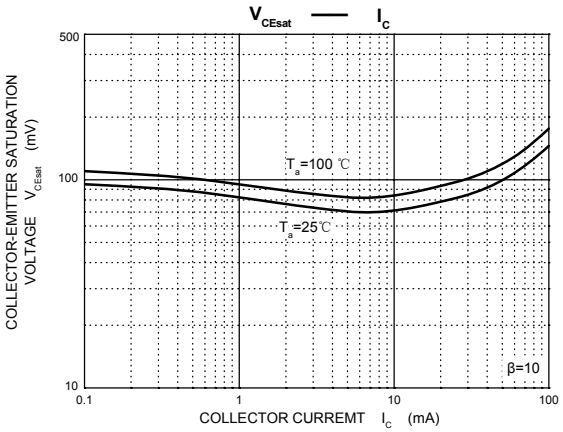
ELECTRICAL CHARACTERISTICS (T_a=25℃ unless otherwise specified)

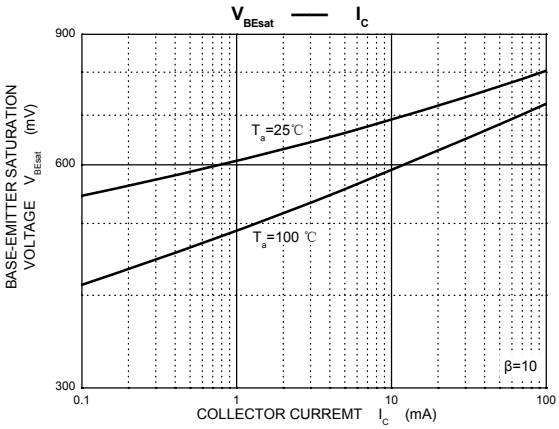
Parameter	Symbol	Test conditions	Min	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	I_C= 100μA,I_E=0	300		V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	I_C= 1mA, I_B=0	300		V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	I_E= 100μA, I_C=0	5		V
Collector cut-off current	I_{CBO}	V_{CB}=200V, I_E=0		0.25	μA
Emitter cut-off current	I_{EBO}	V_{EB}= 5V, I_C=0		0.1	μA
DC current gain	$h_{FE(1)}$	V_{CE}= 10V, I_C= 1mA	60		
	$h_{FE(2)}$	V_{CE}= 10V, I_C=10mA	100	200	
	$h_{FE(3)}$	V_{CE}=10V, I_C=30mA	60		
Collector-emitter saturation voltage	$V_{CE(sat)}$	I_C=20mA, I_B= 2mA		0.2	V
Base-emitter saturation voltage	$V_{BE(sat)}$	I_C= 20mA, I_B=2mA		0.9	V
Transition frequency	f_T	V_{CE}= 20V, I_C= 10mA, f=30MHz	50		MHz

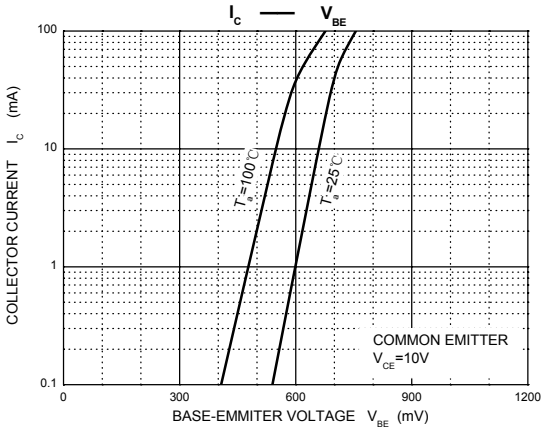
Typical Characteristics

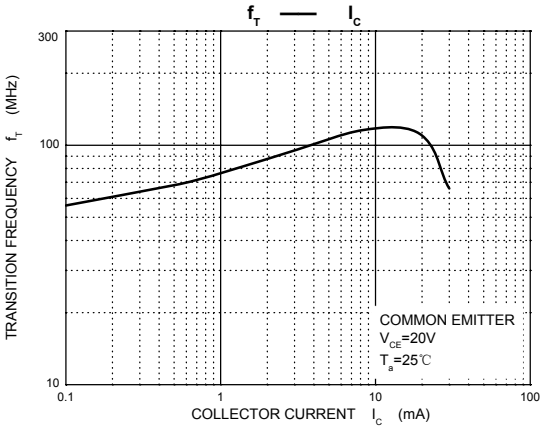


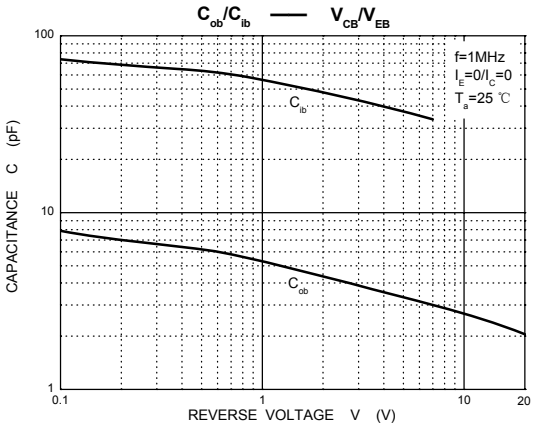


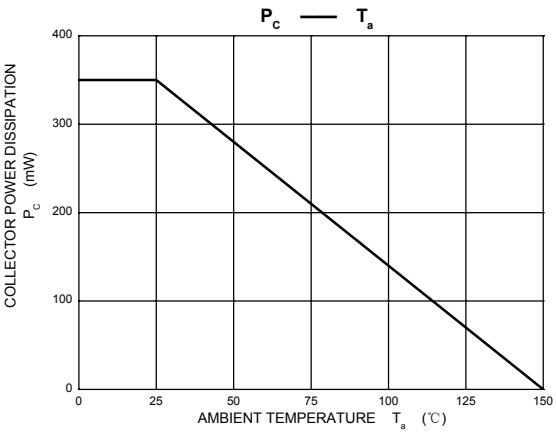


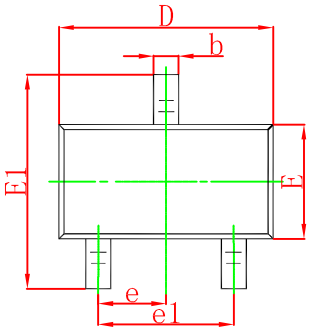


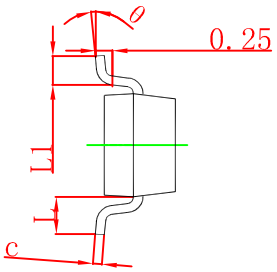


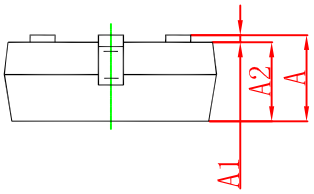






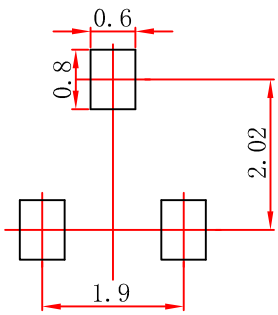






Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

SOT-23 Suggested Pad Layout



Note:
1.Controlling dimension:in millimeters.
2.General tolerance:± 0.05mm.
3.The pad layout is for reference purposes only.